

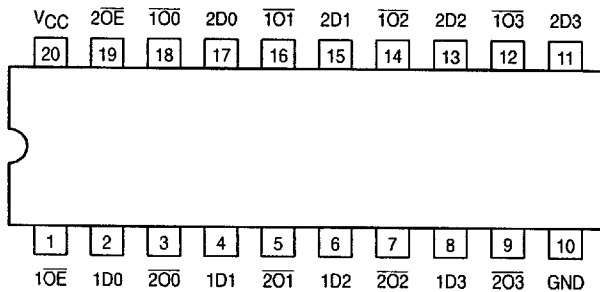
Low-Voltage Quiet CMOS Octal Buffer (3-State, Inverting)

The MC74LVQ240 is a high performance, inverting octal buffer operating from a 2.7 to 3.6V supply. The MC74LVQ240 is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 12mA at the outputs. The Output Enable (\overline{OE}) input, when HIGH, disables the output by placing them in a HIGH Z condition.

- Designed for 2.7 to 3.6V V_{CC} Operation – Ideal for Low Power/Low Noise Applications
- Guaranteed Simultaneous Switching Noise Level and Dynamic Threshold Performance
- Guaranteed Skew Specifications
- Guaranteed Incident Wave Switching into 75 Ω
- Low Static Supply Current (10 μ A) Substantially Reduces System Power Requirements
- Latchup Performance Exceeds 500mA
- ESD Performance: Human Body Model >2000V

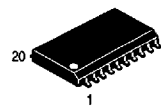
Pinout: 20-Lead (Top View)



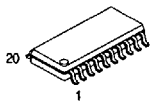
MC74LVQ240

LVQ

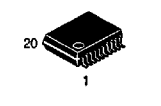
**LOW-VOLTAGE CMOS
OCTAL BUFFER**



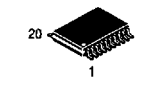
DW SUFFIX
PLASTIC SOIC
CASE 751D-04



M SUFFIX
PLASTIC SOIC EIAJ
CASE 967-01



SD SUFFIX
PLASTIC SSOP
CASE 940C-03



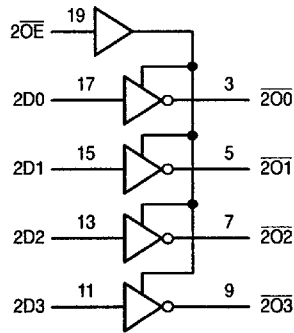
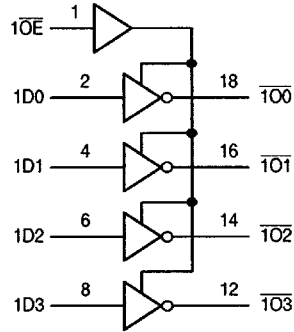
DT SUFFIX
PLASTIC TSSOP
CASE 948E-02

PIN NAMES

Pins	Function
\overline{nOE}	Output Enable Inputs
1Dn, 2Dn	Data Inputs
1On, 2On	3-State Outputs

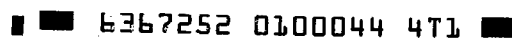


LOGIC DIAGRAM



INPUTS		OUTPUTS
1OE 2OE	1Dn 2Dn	1On, 2On
L	L	L
L	H	H
H	X	Z

H = High Voltage Level; L = Low Voltage Level; Z = High Impedance State; X = High or Low Voltage Level and Transitions Are Acceptable, for I_{CC} reasons, DO NOT FLOAT Inputs



ABSOLUTE MAXIMUM RATINGS*

Symbol	Parameter	Value	Condition	Unit
V _{CC}	DC Supply Voltage	-0.5 to +7.0		V
V _I	DC Input Voltage	$-0.5 \leq V_I \leq V_{CC} + 0.5V$		V
V _O	DC Output Voltage	$-0.5 \leq V_O \leq V_{CC} + 0.5$	Output in HIGH or LOW State	V
I _{IK}	DC Input Diode Current	-20	V _I = -0.5V	mA
		+20	V _I = V _{CC} + 0.5V	mA
I _{OK}	DC Output Diode Current	-20	V _O = -0.5V	mA
		+20	V _I = V _{CC} + 0.5V	mA
I _O	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current	±400		mA
I _{GND}	DC Ground Current	±400		mA
T _{STG}	Storage Temperature Range	-65 to +150		°C

* Absolute maximum continuous ratings are those values beyond which damage to the device may occur. Exposure to these conditions or conditions beyond those indicated may adversely affect device reliability. Functional operation under absolute-maximum-rated conditions is not implied.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Typ	Max	Unit
V _{CC}	Supply Voltage	2.0	3.3	3.6	V
V _I	Input Voltage	0		V _{CC}	V
V _O	Output Voltage	0		V _{CC}	V
T _A	Operating Free-Air Temperature	-40		+85	°C
ΔV/Δt	Input Transition Rise or Fall Rate, V _{IN} from 0.8V to 2.0V, V _{CC} = 3.0V	0		125	mV/ns

DC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic	Condition	T _A = -40°C to +85°C		Unit
			Min	Max	
V _{IH}	HIGH Level Input Voltage (Note 1)	2.7V ≤ V _{CC} ≤ 3.6V, V _O = 0.1V or V _{CC} - 0.1V	2.0		V
V _{IL}	LOW Level Input Voltage (Note 1)	2.7V ≤ V _{CC} ≤ 3.6V, V _O = 0.1V or V _{CC} - 0.1V		0.8	V
V _{OH}	HIGH Level Output Voltage	2.7V ≤ V _{CC} ≤ 3.6V; I _{OH} = -50μA	V _{CC} - 0.1		V
		V _{CC} = 2.7V; I _{OH} = -12mA	2.2		
		V _{CC} = 3.0V; I _{OH} = -12mA	2.48		
V _{OL}	LOW Level Output Voltage	2.7V ≤ V _{CC} ≤ 3.6V; I _{OL} = 50μA		0.1	V
		2.7V ≤ V _{CC} ≤ 3.6V; I _{OL} = 12mA		0.4	
I _I	Input Leakage Current	2.7V ≤ V _{CC} ≤ 3.6V; V _I = V _{CC} , GND		±1.0	μA
I _{OZ}	Maximum 3-State Leakage Current	V _I (\overline{OE}) = V _{IL} , V _{IH} ; V _I , V _O = V _{CC} , GND		±2.5	μA
I _{OLD}	Minimum Dynamic Output Current (Note 2)	V _{CC} = 3.6V; V _{OLD} = 0.8V Max		36	mA
I _{OHD}		V _{CC} = 3.6V; V _{OHD} = 2.0V Min		-25	mA
I _{CC}	Quiescent Supply Current	2.7V ≤ V _{CC} ≤ 3.6V; V _I = V _{CC} , GND		10	μA

1. These values of V_I are used to test DC electrical characteristics only. Functional test should use V_{IH} ≥ 2.4V, V_{IL} ≤ 0.5V.

2. Incident wave switching on transmission lines with impedances as low as 75Ω for commercial temperature range is guaranteed. Maximum test duration is 2ms, one output loaded at a time.

MC74LVQ240

DYNAMIC SWITCHING CHARACTERISTICS ($V_{CC} = 3.3V$)

Symbol	Characteristic	Condition	$T_A = +25^\circ C$			Unit
			Min	Typ	Max	
VOLP	Dynamic LOW Peak Voltage (Note 1)	$C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V$		0.6	1.0	V
VOLV	Dynamic LOW Valley Voltage (Note 1)	$C_L = 50pF, V_{IH} = 3.3V, V_{IL} = 0V$		-0.5	-1.0	V
V _{IHD}	High Level Dynamic Input Voltage (Note 2)	Input-Under-Test Switching 0V to Threshold, $f=1MHz$		1.5	2.0	V
V _{ILD}	Low Level Dynamic Input Voltage (Note 2)	Input-Under-Test Switching 3.3V to Threshold, $f=1MHz$		1.5	0.8	V

- Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW. The remaining output is measured in the LOW state.
- Number of data inputs is defined as "n" switching, "n-1" inputs switching 0V to 3.3V.

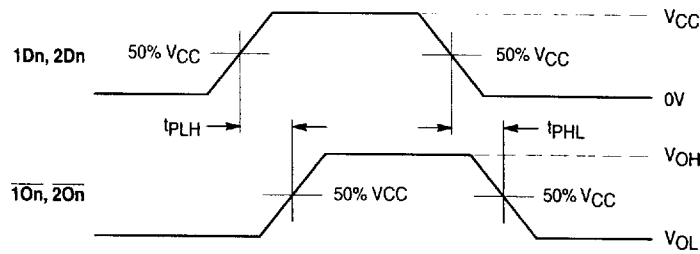
AC CHARACTERISTICS ($t_R = t_F = 2.5ns; C_L = 50pF; R_L = 500\Omega$)

Symbol	Parameter	Limits									Unit
		$T_A = +25^\circ C$						$T_A = -40^\circ C$ to $+85^\circ C$			
		$V_{CC} = 3.0V$ to $3.6V$			$V_{CC} = 2.7V$			$V_{CC} = 3.0V$ to $3.6V$		$V_{CC} = 2.7V$	
		Min	Typ	Max	Min	Typ	Max	Min	Max	Max	
t _{PLH} t _{PHL}	Propagation Delay Input to Output	2.0 2.0	6.0 6.0	9.5 9.5	2.0 2.0	7.0 7.0	11.0 11.0	2.0 2.0	10.5 10.5	12.0 12.0	ns
t _{PZH} t _{PZL}	Output Enable Time to High and Low Level	2.5 2.5	7.5 7.5	11.0 11.0	2.5 2.5	9.0 9.0	13.0 13.0	2.5 2.5	12.0 12.0	14.0 14.0	ns
t _{PHZ} t _{PLZ}	Output Disable Time From High and Low Level	1.0 1.0	7.0 7.0	10.5 10.5	1.0 1.0	9.0 9.0	13.0 13.0	1.0 1.0	11.5 11.5	14.0 14.0	ns
t _{OSSL} t _{OSLH}	Output-to-Output Skew (Note 1)		1.0 1.0	1.5 1.5		1.0 1.0	1.5 1.5		1.5 1.5		ns

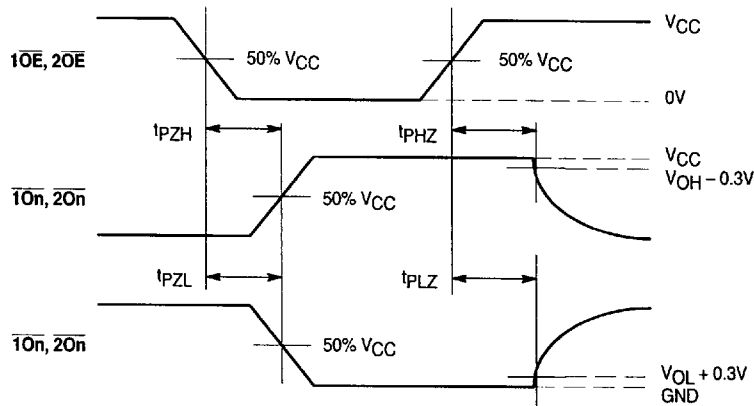
- Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSSL}) or LOW-to-HIGH (t_{OSLH}); parameter guaranteed by design.

CAPACITIVE CHARACTERISTICS

Symbol	Parameter	Condition	Typical	Unit
C _{PD}	Power Dissipation Capacitance	10MHz, $V_{CC} = 3.3V, V_I = 0V$ or V_{CC}	22	pF
C _{IN}	Input Capacitance	$V_{CC} = \text{Open}, V_I = 0V$ or V_{CC}	4.5	pF

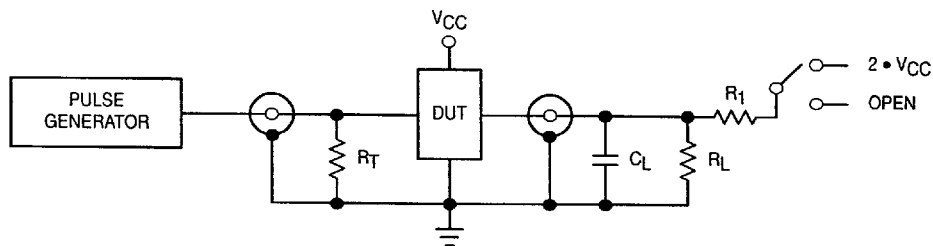


WAVEFORM 1 – PROPAGATION DELAYS
 $t_R = t_F = 2.5\text{ns}$, 10% to 90%; $f = 1\text{MHz}$; $t_W = 500\text{ns}$



WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES
 $t_R = t_F = 2.5\text{ns}$, 10% to 90%; $f = 1\text{MHz}$; $t_W = 500\text{ns}$

Figure 1. AC Waveforms



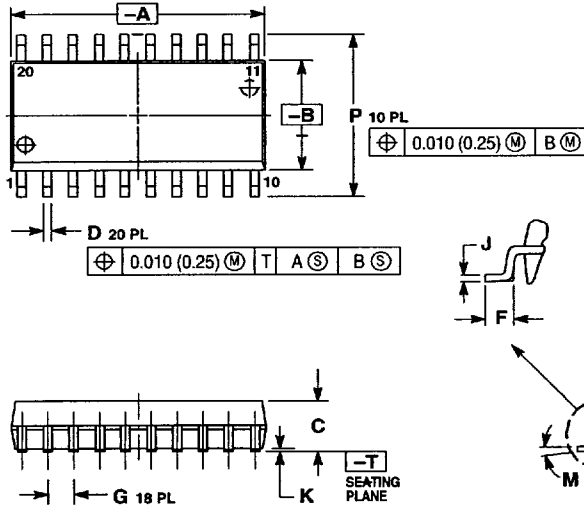
TEST	SWITCH
t_{PLH} , t_{PHL}	Open
t_{PZL} , t_{PLZ}	$2 \cdot V_{CC}$
Open Collector/Drain t_{PLH} and t_{PHL}	$2 \cdot V_{CC}$
t_{PZH} , t_{PHZ}	Open

$C_L = 50\text{pF}$ or equivalent (Includes jig and probe capacitance)
 $R_L = R_1 = 500\Omega$ or equivalent
 $R_T = Z_{OUT}$ of pulse generator (typically 50Ω)

Figure 2. Test Circuit

OUTLINE DIMENSIONS

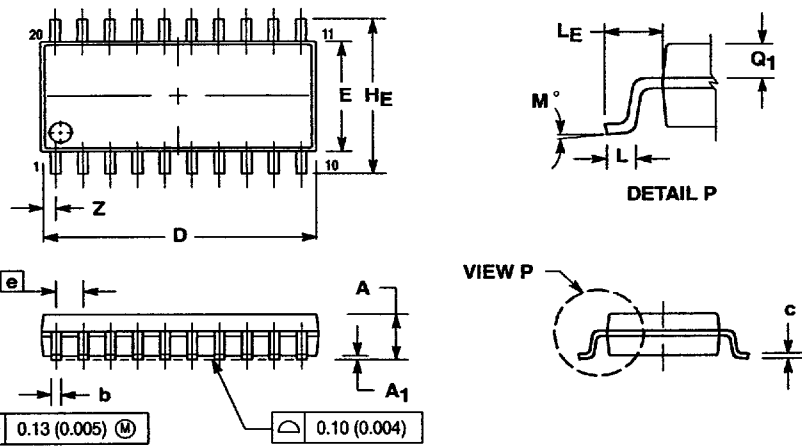
DW SUFFIX
PLASTIC SOIC PACKAGE
CASE 751D-04
ISSUE E



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.150 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 (0.005) TOTAL IN EXCESS OF D DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	12.65	12.95	0.499	0.510
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27 BSC		0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029

M SUFFIX
PLASTIC SOIC EIAJ PACKAGE
CASE 967-01
ISSUE O



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A1	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	12.35	12.80	0.486	0.504
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q1	0.70	0.90	0.028	0.035
Z	---	0.81	---	0.032

OUTLINE DIMENSIONS

